

# **TEA1995T**

## **GreenChip dual synchronous rectifier controller**

Rev. 3 — 5 December 2017

Product data sheet

### 1 General description

The TEA1995T is the first product of a new generation of Synchronous Rectifier (SR) controller ICs for switched mode power supplies. It incorporates an adaptive gate drive method for maximum efficiency at any load.

The TEA1995T is a dedicated controller IC for synchronous rectification on the secondary side of resonant converters. It has two driver stages for driving the SR MOSFETs, which rectify the outputs of the central tap secondary transformer windings. The two gate driver stages have their own sensing inputs and operate independently.

The TEA1995T can also be used in multi-output flyback converters with the SR MOSFET placed at the low side.

The TEA1995T is fabricated in a Silicon-On-Insulator (SOI) process.

#### 2 Features and benefits

#### 2.1 Efficiency features

- · Adaptive gate drive for maximum efficiency at any load
- Supply current in energy save operation below 200 μA

#### 2.2 Application features

- Wide supply voltage range from 4.5 V to 38 V
- Dual synchronous rectification for LLC resonant in SO8 package
- Synchronous rectification for multi-output flyback converters
- Supports 5 V operation with logic level SR MOSFETs
- Differential inputs for sensing the drain and source voltages of each SR MOSFET

#### 2.3 Control features

- · SR control without minimum on-time
- Adaptive gate drive for fast turn-off at the end of conduction
- UnderVoltage LockOut (UVLO) protection with active gate pull-down



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### 3 Applications

The TEA1995T is intended for resonant power supplies. In such applications, it can drive two external synchronous rectifier MOSFETs for the rectification of the voltages on the two secondary windings of the transformer. These MOSFETs replace diodes. It can be used in all power supplies requiring high efficiency:

- Adapters
- · Power supplies for desktop PC and all-in-one PC
- · Power supplies for television
- Power supplies for servers

### 4 Ordering information

#### **Table 1. Ordering information**

Type number	Package		
	Name	Description	Version
TEA1995T/1	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

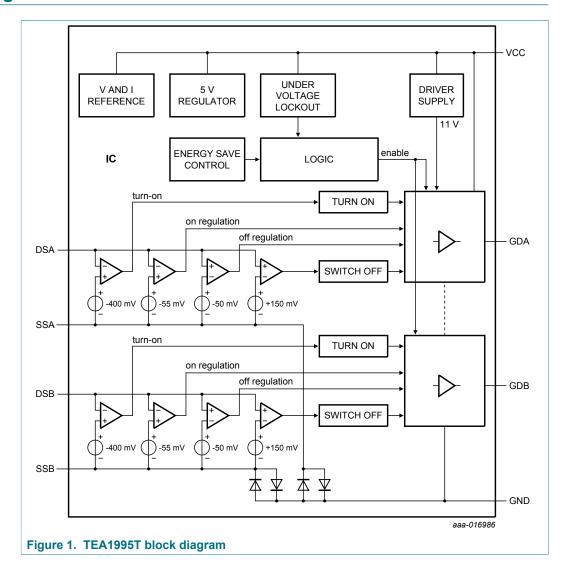
### 5 Marking

#### Table 2. Marking

Type number	Marking code
TEA1995T/1	TEA1995

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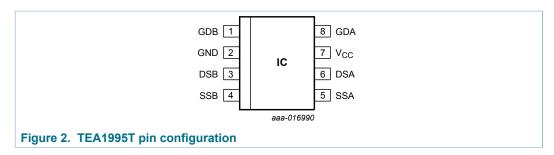
## 6 Block diagram



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## 7 Pinning information

### 7.1 Pinning



### 7.2 Pin description

Table 3. Pin description

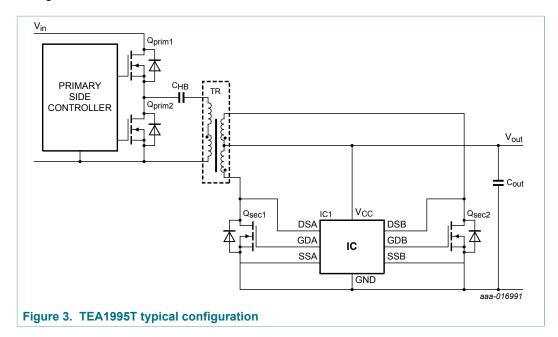
Symbol	Pin	Description
GDB	1	gate drive output MOSFET B
GND	2	ground
DSB	3	drain sense input for synchronous timing MOSFET B
SSB	4	source sense input MOSFET B
SSA	5	source sense input MOSFET A
DSA	6	drain sense input for synchronous timing MOSFET A
V <sub>CC</sub>	7	supply voltage
GDA	8	gate drive output MOSFET A

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### 8 Functional description

#### 8.1 Introduction

The TEA1995T is a controller IC for synchronous rectification. It is perfectly suited to be used in resonant applications. It can drive two synchronous rectifier MOSFETs on the secondary side of the central tap transformer winding. Figure 3 shows a typical configuration.



#### 8.2 Start-up and undervoltage lockout (V<sub>CC</sub> pin)

When the voltage on the  $V_{CC}$  pin exceeds  $V_{start}$ , the IC leaves the UVLO state and activates the SR circuitry. When the voltage drops to below  $V_{stop}$ , the IC reenters the UVLO state. The SR MOSFET gate driver outputs are actively kept low. For proper operation, the  $V_{CC}$  pin must be decoupled with an extra capacitor (not only with  $C_{out}$ ) between the  $V_{CC}$  pin and the GND pin. To reduce inductance effects because of high gate driver currents, the extra capacitor must be connected as close as possible to the IC.

#### 8.3 Drain sense (DSA and DSB pins)

The drain sense pins are input pins capable of handling input voltages up to 100 V. At positive drain sense voltages, the gate driver is in off-mode with pulled-down gate driver pins (pins GDA or GDB). At negative drain sense voltages, the IC enables the SR through sensing the drain source differential voltage.

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#### 8.4 Synchronous Rectification (SR; DSA, SSA, DSB, and SSB pins)

The IC senses the voltage difference between the drain sense (pins DSA and DSB) and the source sense (pins SSA and SSB) connections. The drain source differential voltage of the SR MOSFET is used to drive the gate of the SR MOSFET.

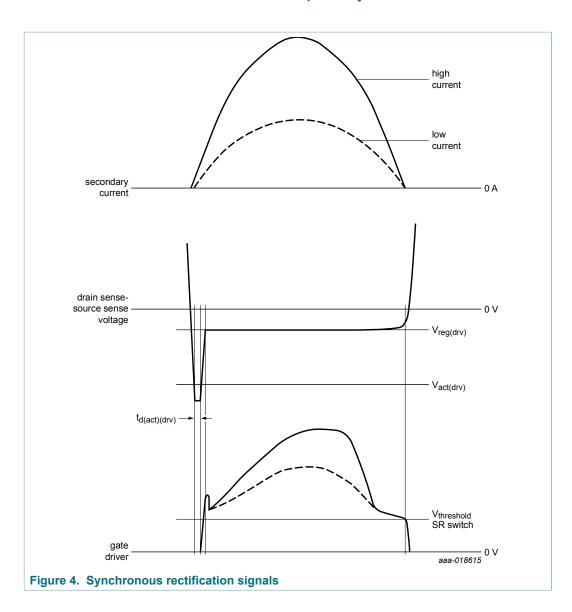
When this absolute voltage difference is higher than  $V_{act(drv)}$ , the corresponding gate driver output turns on the external SR MOSFET. When the external SR MOSFET is switched on, the absolute voltage difference between the drain and the source sense connections drops to below  $V_{act(drv)}$ . The regulation phase follows the turn-on phase.

In the regulation phase, the IC regulates the difference between the drain and the source sense inputs to an absolute level ( $V_{reg(drv)}$ ). When the absolute difference is higher than  $V_{reg(drv)}$ , the gate driver output increases the gate voltage of the external SR MOSFET until the  $V_{reg(drv)}$  level is reached. The SR MOSFET does not switch off at low currents. The IC operates without minimum on-time.

When the absolute difference is lower than  $V_{deact(drv)}$ , the gate driver output decreases the gate voltage of the external SR MOSFET. The voltage waveform on the gate of the SR MOSFET follows the waveform of the current through the SR MOSFET. When the current through the external SR MOSFET reaches zero, the SR MOSFET is quickly switched off.

After the SR MOSFET switch-off, the drain voltage increases. For a drain voltage above  $V_{\text{swoff}}$ , a low ohmic gate pull-down of  $R_{\text{pd}(G)}$  keeps the gate of the SR MOSFET switched off.

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#### 8.5 Gate driver (GDA and GDB pins)

The gate driver circuit charges the gate of the external SR MOSFET during the rising part of the current. The driver circuit discharges the gate during the falling part of the current. The gate driver has a source capability of typically  $I_{\text{source}}$  and a sink capability of typically  $I_{\text{sink}}$ . The source and sink capability allow a fast turn-on and a fast turn-off of the external SR MOSFET.

The maximum driver output voltage is limited to  $V_{G(max)}$ . This high output voltage drives all MOSFET brands to the minimum on-state resistance.

In applications where the IC is supplied with 5 V, the maximum output voltage of the driver is limited to 5 V. Logic level SR MOSFETs can be used.

During start-up conditions ( $V_{CC} < V_{start}$ ) and UVLO, the driver output voltage is actively pulled low.

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#### 8.6 Source sense connection (SSA and SSB pins)

The IC is equipped with additional source sense pins (SSA and SSB). These pins are used for the measurement of the SR MOSFET drain-to-source voltage. The source sense input must be connected as close as possible to the source pin of the external SR MOSFET. It minimizes errors caused by voltage difference on PCB tracks because of parasitic inductance in combination with large dI/dt values.

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## **Limiting values**

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Voltages				'		
V <sub>CC</sub>	supply voltage			-0.4	+38	V
V <sub>sense(D)A</sub>	drain sense voltage A	DC		-0.8	+100	V
V <sub>sense(D)B</sub>	drain sense voltage B	DC		-0.8	+100	V
V <sub>sense(S)A</sub>	source sense voltage A	DC		-0.4	+0.4	V
V <sub>sense(S)B</sub>	source sense voltage B	DC		-0.4	+0.4	V
$V_{GDA}$	voltage on pin GDA	DC	[1]	-0.4	+13.0	V
$V_{GDB}$	voltage on pin GDB	DC	[1]	-0.4	+13.0	V
General					1	
P <sub>tot</sub>	total power dissipation			-	0.5	W
f <sub>max</sub>	maximum frequency	if not limited by P <sub>tot</sub>		-	500	kHz
T <sub>stg</sub>	storage temperature			-55	+150	°C
Tj	junction temperature			-40	+150	°C
ElectroStati	c Discharge (ESD)					
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM)	[2]	-	2000	V
		Charged Device Model (CDM)	[3]	-	500	V

- [1] These pins are output pins that are forced by the IC (see <u>Table 6</u>) [2] Human body model: Equivalent to discharging a 100 pF capacitor through a 1.5 k $\Omega$  series resistor. [3] Charged device model: Equivalent to charging the IC and discharging each pin over a 1  $\Omega$  resistor.

### 10 Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC test board	140	K/W
R <sub>th(j-c)</sub>	thermal resistance from junction to case	JEDEC test board	90	K/W

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### 11 Characteristics

#### **Table 6. Characteristics**

 $T_{amb}$  = 25 °C;  $V_{CC}$  = 12 V;  $C_{GDA}/C_{GDB}$  = 10 nF (capacitors between GDA and GND) and between GDB and GND). All voltages are measured with respect to ground (pin 2). Currents are positive when flowing into the IC, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply vol	tage management (pin V <sub>CC</sub> )					
V <sub>start</sub>	start voltage		4.35	4.55	4.75	V
V <sub>stop</sub>	stop voltage		4.0	4.2	4.4	V
I <sub>CC(oper)</sub>	operating supply current	energy-save	140	160	180	μΑ
		normal operation (without gate charge)	0.9	1.1	1.3	mA
t <sub>act(es)</sub>	energy save mode activation time		85	110	135	μs
Synchrono	ous rectification sense input (pins D	SA, SSA, DSB, and SSB)				
V <sub>act(drv)</sub>	driver activation voltage	$V_{\text{sense(S)A}}/V_{\text{sense(S)B}} = 0 \text{ V}$	-450	-400	-350	mV
V <sub>reg(drv)</sub>	driver regulation voltage	$V_{\text{sense(S)A}}/V_{\text{sense(S)B}} = 0 \text{ V}$	-60	-55	-50	mV
V <sub>swoff</sub>	switch-off voltage	$V_{\text{sense(S)A}}/V_{\text{sense(S)B}} = 0 \text{ V}$	90	150	200	mV
t <sub>d(act)(drv)</sub>	driver activation delay time	$\begin{split} &V_{sense(S)A}/V_{sense(S)B} = 0 \text{ V;} \\ &\text{normal operation;} \\ &\text{time from step on } V_{DSA}/V_{DSB} \text{ (2 V to } \\ &-0.5 \text{ V) to rising of } V_{GDA}/V_{GDB} \text{ at 10 \%} \\ &\text{of end value} \end{split}$	-	80	-	ns
t <sub>d(deact)(drv)</sub>	driver deactivation delay time	$\begin{split} &V_{\text{sense(S)A}}/V_{\text{sense(S)B}} = 0 \text{ V;} \\ &\text{normal operation;} \\ &\text{time from step on } V_{\text{DSA}}/V_{\text{DSB}} \text{ (-0.5 V)} \\ &\text{to 2 V) to falling of } V_{\text{GDA}}/V_{\text{GDB}} \text{ at 90 \%} \\ &\text{of begin value} \end{split}$	-	40	-	ns
Gate drive	r (pins GDA and GDB)					
I <sub>source</sub>	source current	peak current at $V_{CC} = 5 \text{ V; } V_{DS} = -0.5 \text{ V; } V_{G} = 0 \text{ V}$	-	-0.4	-	Α
		peak current at $V_{CC}$ = 12 V; $V_{DS}$ = -0.5 V; $V_{G}$ = 0 V	-	-1.0	-	Α
I <sub>sink</sub>	sink current	regulation current at V <sub>CC</sub> = 5 V; V <sub>DS</sub> = 0 V; V <sub>G</sub> = 5 V	-	90	-	mA
		regulation current at $V_{CC}$ = 12 V; $V_{DS}$ = 0 V; $V_{G}$ = 10 V	-	100	-	mA
		peak current at $V_{CC} = 5 \text{ V}$ ; $V_{DS} = 4 \text{ V}$ ; $V_{G} = 4 \text{ V}$	-	0.6	-	Α
		peak current at $V_{CC}$ = 12 V; $V_{DS}$ = 4 V; $V_{G}$ = 4 V	-	1.0	-	Α
$R_{pd(G)}$	gate pull-down resistance	in off-state; $V_{DSA}/V_{DSB} = 4 \text{ V}$ ; $I_{GDA}/I_{GDB} = 30 \text{ mA}$ ; $V_{CC} = 12 \text{ V}$	3.2	4	5	Ω

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{G(max)}$	maximum gate voltage	$V_{GDA}/V_{GDB}$ at $V_{CC}$ = 5 V	4.9	4.95	5.0	V
		$V_{GDA}/V_{GDB}$ at $V_{CC}$ = 12 V	10.5	10.75	11.0	V
		$V_{GDA}/V_{GDB}$ at $V_{CC}$ = 15 V to 38 V	11	12	13	V

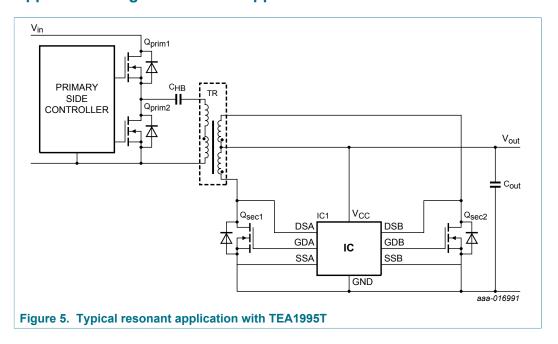
### 12 Application information

A resonant switched mode power supply with the TEA1995T consists of a primary side half-bridge, a transformer, a resonant capacitor, and an output stage. To obtain low conduction loss rectification, SR MOSFETs are used in the output stage. The TEA1995T controls these SR MOSFETs.

The gate drive voltage for the SR switch is derived from the voltage difference between the corresponding drain sense and source sense pins.

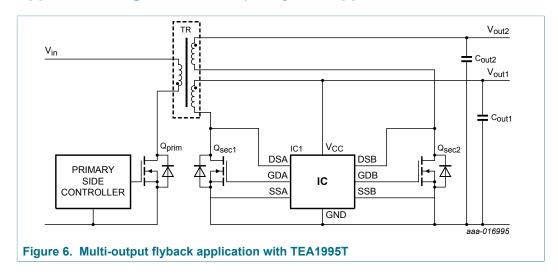
Special attention must be paid to the connection of the drain sense and source sense pins. The voltages measured on these pins are used for gate drive voltage. Wrong measurement results in a less efficient gate drive because the gate voltage is either too low or too high. The connections to these pins must not interfere with the power wiring. The power wiring conducts currents with high dl/dt values. It can easily cause measurement errors resulting from induced voltages due to parasitic inductances. The separate source-sense pins enable the direct sensing of the source voltage of the external MOSFETs. Using the current carrying power ground tracks is not allowed.

#### 12.1 Application diagram resonant application



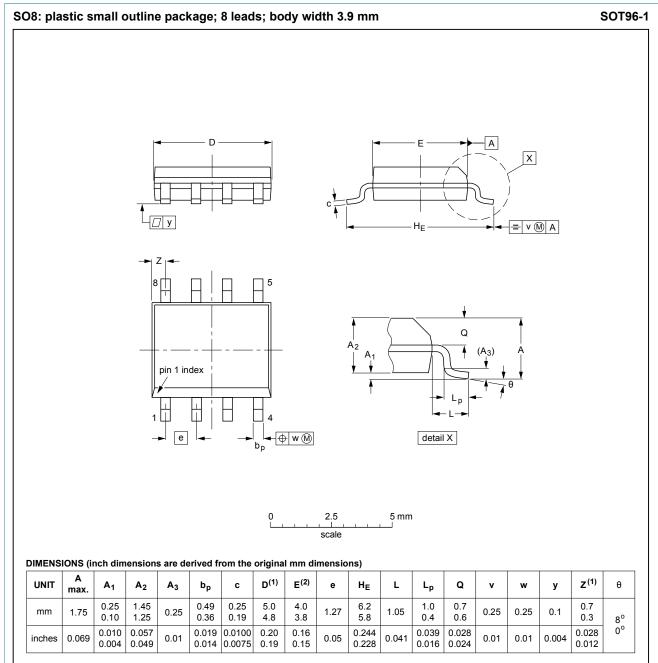
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### 12.2 Application diagram multi-output flyback application



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### 13 Package outline



#### Notes

- 1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT96-1	076E03	MS-012			<del>99-12-27</del> 03-02-18

Figure 7. Package outline SOT96-1 (SO8)

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### 14 Abbreviations

Table 7. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MOSFET	Metal-Oxide-Semiconductor Field-Effect Transistor
SOI	Silicon-On-Insulator
SR	Synchronous Rectification
UVLO	UnderVoltage LockOut

### GreenChip dual synchronous rectifier controller

## 15 Revision history

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TEA1995T v.3	20171205	Product data sheet	-	TEA1995T v.2
Modifications:	Section 10 "The	rmal characteristics" has been	updated.	
TEA1995T v.2	20161130	Product data sheet	-	TEA1995T v.1
TEA1995T v.1	20150730	Product data sheet	-	-

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### 16 Legal information

#### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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